Peak Reducing EMI Solution

Features

- **Cypress PREMIS™ family offering**
- **Generates an EMI optimized clocking signal at the output**
- **Selectable input to output frequency**
- **Single −1.25% or −3.75% down spread output**
- **Integrated loop filter components**
- **Operates with a 3.3V or 5V supply**
- **Low power CMOS design**
- **Available in 8-pin SOIC (Small Outline Integrated Circuit) or 14-pin TSSOP (Thin Shrink Small Outline Package)**

Key Specifications

Supply Voltages: ....V_{DD} = 3.3V±5%
or V_{DD} = 5V±10%

Frequency Range: .... 28 MHz ≤ F_{in} ≤ 75 MHz

Crystal Reference Range.................. 28 MHz ≤ F_{in} ≤ 40 MHz

Cycle to Cycle Jitter: .... 300 ps (max)

Selectable Spread Percentage: .... −1.25% or −3.75%

Output Duty Cycle: .... 40/60% (worst case)

Output Rise and Fall Time: .... 5 ns (max)

Table 1. Modulation Width Selection

SS%	Output
0	F_{in} ≥ F_{out} ≥ F_{in} − 1.25%
1	F_{in} ≥ F_{out} ≥ F_{in} − 3.75%

Table 2. Frequency Range Selection

		W181 Option#		
FS2	FS1	-01 (MHz)	-02 (MHz)	-03 (MHz)
0	0	28 ≤ F_{IN} ≤ 38	28 ≤ F_{IN} ≤ 38	N/A
0	1	38 ≤ F_{IN} ≤ 48	38 ≤ F_{IN} ≤ 48	N/A
1	0	46 ≤ F_{IN} ≤ 60	N/A	46 ≤ F_{IN} ≤ 60
1	1	58 ≤ F_{IN} ≤ 75	N/A	58 ≤ F_{IN} ≤ 75

Simplified Block Diagram
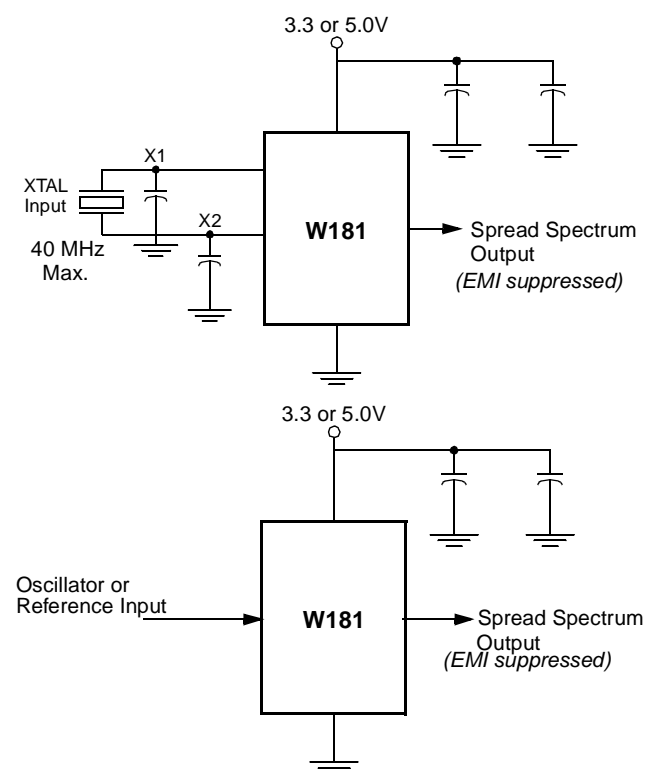
Pin Configurations
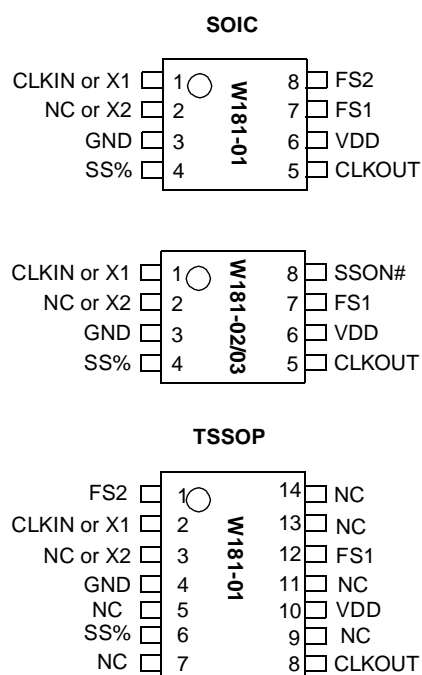
PREMIS is a trademark of Cypress Semiconductor Corporation.

Pin Definitions

Pin Name	Pin No. (SOIC)	Pin No. (TSSOP)(-01)	Pin Type	Pin Description
CLKOUT	5	8	O	**Output Modulated Frequency**: Frequency modulated copy of the unmodulated input clock (SSON# asserted).
CLKIN or X1	1	2	I	**Crystal Connection or External Reference Frequency Input:** This pin has dual functions. It may either be connected to an external crystal, or to an external reference clock.
NC or X2	2	3	I	**Crystal Connection:** If using an external reference, this pin must be left unconnected.
SSON#	8(-02/-03)	--	I	**Spread Spectrum Control (Active LOW):** Asserting this signal (active LOW) turns the internal modulation waveform on. This pin has an internal pull-down resistor.
FS1:2	7, 8 (-01)	12, 1	I	**Frequency Selection Bit(s) 1 and 2:** These pins select the frequency range of operation. Refer to *Table 2*. These pins have internal pull-up resistors.
SS%	4	6	I	**Modulation Width Selection:** When Spread Spectrum feature is turned on, this pin is used to select the amount of variation and peak EMI reduction that is desired on the output signal.
VDD	6	10	P	**Power Connection:** Connected to 3.3V or 5V power supply.
GND	3	4	G	**Ground Connection:** Connect all ground pins to the common system ground plane.
NC		5, 7, 9, 11, 13, 14	NC	**No Connection**

Overview

The W181 products are one series of devices in the Cypress PREMIS family. The PREMIS family incorporates the latest advances in PLL spread spectrum frequency synthesizer techniques. By frequency modulating the output with a low-frequency carrier, peak EMI is greatly reduced. Use of this technology allows systems to pass increasingly difficult EMI testing without resorting to costly shielding or redesign.

In a system, not only is EMI reduced in the various clock lines, but also in all signals which are synchronized to the clock. Therefore, the benefits of using this technology increase with the number of address and data lines in the system. The Simplified Block Diagram on page 1 shows a simple implementation.

Functional Description

The W181 uses a phase-locked loop (PLL) to frequency modulate an input clock. The result is an output clock whose frequency is slowly swept over a narrow band near the input signal. The basic circuit topology is shown in *Figure 1*. The input reference signal is divided by Q and fed to the phase detector. A signal from the VCO is divided by P and fed back to the phase detector also. The PLL will force the frequency of the VCO output signal to change until the divided output signal and the divided reference signal match at the phase detector input. The output frequency is then equal to the ratio of P/Q

times the reference frequency. (Note: For the W181 the output frequency is equal to the input frequency.) The unique feature of the Spread Spectrum Frequency Timing Generator is that a modulating waveform is superimposed at the input to the VCO. This causes the VCO output to be slowly swept across a pre-determined frequency band.

Because the modulating frequency is typically 1000 times slower than the fundamental clock, the spread spectrum process has little impact on system performance.

Frequency Selection With SSFTG

In Spread Spectrum Frequency Timing Generation, EMI reduction depends on the shape, modulation percentage, and frequency of the modulating waveform. While the shape and frequency of the modulating waveform are fixed for a given frequency, the modulation percentage may be varied.

Using frequency select bits (FS1:2 pins), the frequency range can be set. Spreading percentage is set to be –1.25% (see *Table 1*).

A larger spreading percentage improves EMI reduction. However, large spread percentages may either exceed system maximum frequency ratings or lower the average frequency to a point where performance is affected. For these reasons, spreading percentages between 0.5% and 2.5% are most common.
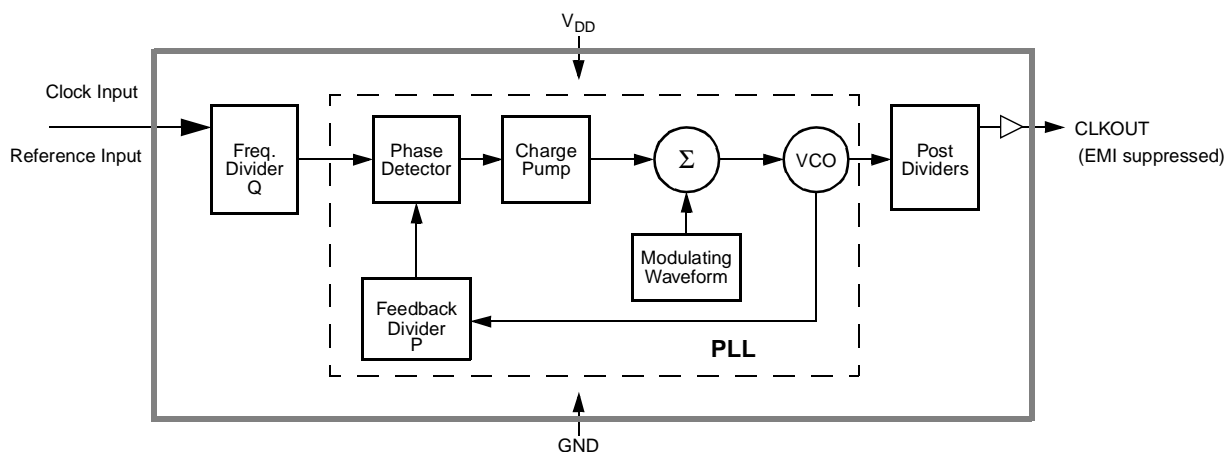

Figure 1. Functional Block Diagram

Spread Spectrum Frequency Timing Generation

The benefits of using Spread Spectrum Frequency Timing Generation are depicted in *Figure 2*. An EMI emission profile of a clock harmonic is shown.

Contrast the typical clock EMI with the Cypress Spread Spectrum Frequency Timing Generation EMI. Notice the spike in the typical clock. This spike can make systems fail quasi-peak EMI testing. The FCC and other regulatory agencies test for peak emissions. With spread spectrum enabled, the peak energy is much lower (at least 8 dB) because the energy is spread out across a wider bandwidth.

Modulating Waveform

The shape of the modulating waveform is critical to EMI reduction. The modulation scheme used to accomplish the maximum reduction in EMI is shown in *Figure 3*. The period of the modulation is shown as a percentage of the period length along the X axis. The amount that the frequency is varied is shown along the Y axis, also shown as a percentage of the total frequency spread.

Cypress frequency selection tables express the modulation percentage in two ways. The first method displays the spreading frequency band as a percent of the programmed average output frequency, symmetric about the programmed average frequency. This method is always shown using the expression $f_{Center} \pm X_{MOD}\%$ in the frequency spread selection table.

The second approach is to specify the maximum operating frequency and the spreading band as a percentage of this frequency. The output signal is swept from the lower edge of the band to the maximum frequency. The expression for this approach is $f_{MAX} - X_{MOD}\%$. Whenever this expression is used, Cypress has taken care to ensure that f_{MAX} will never be exceeded. This is important in applications where the clock drives components with tight maximum clock speed specifications.
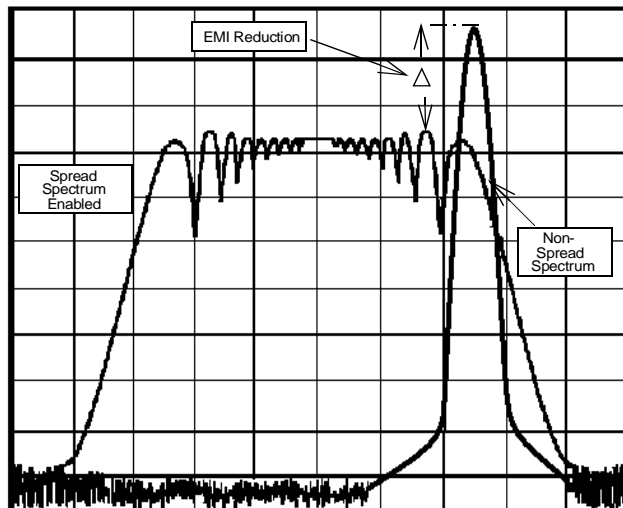

Figure 2. Typical Clock and SSFTG Comparison

SSON# Pin

An internal pull-down resistor defaults the chip into spread spectrum mode. When the SSON# pin is asserted (active LOW) the spreading feature is enabled. Spreading feature is disabled when SSON# is set HIGH (V_{DD}).
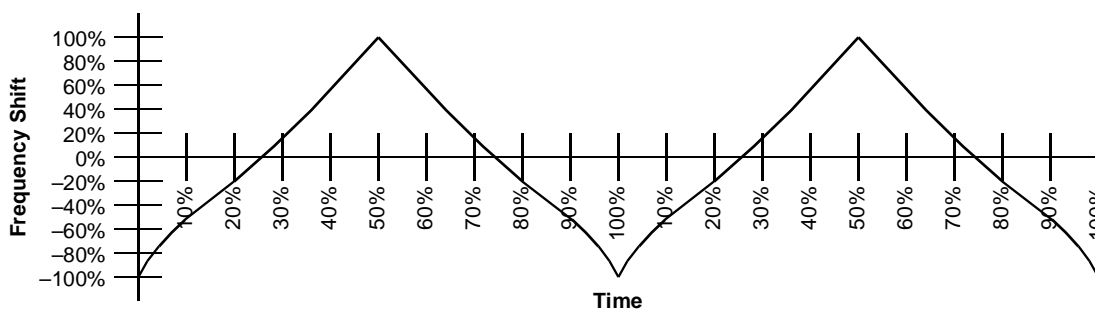

Figure 3. Modulation Waveform Profile

Absolute Maximum Ratings

Stresses greater than those listed in this table may cause permanent damage to the device. These represent a stress rating only. Operation of the device at these or any other conditions above those specified in the operating sections of this specification is not implied. Maximum conditions for extended periods may affect reliability.

Parameter	Description	Rating	Unit
V_{DD}, V_{IN}	Voltage on any pin with respect to GND	−0.5 to +7.0	V
T_{STG}	Storage Temperature	−65 to +150	°C
T_A	Operating Temperature	0 to +70	°C
T_B	Ambient Temperature under Bias	−55 to +125	°C
P_D	Power Dissipation	0.5	W

DC Electrical Characteristics: $0°C < T_A < 70°C$, $V_{DD} = 3.3V \pm 0.3V$

Parameter	Description	Test Condition	Min	Typ	Max	Unit
I_{DD}	Supply Current			18	32	mA
t_{ON}	Power-Up Time	First locked clock cycle after Power Good			5	ms
V_{IL}	Input Low Voltage				0.8	V
V_{IH}	Input High Voltage		2.4			V
V_{OL}	Output Low Voltage				0.4	V
V_{OH}	Output High Voltage		2.4			V
I_{IL}	Input Low Current	Note 1			−100	µA
I_{IH}	Input High Current	Note 1			10	µA
I_{OL}	Output Low Current	@ 0.4V, $V_{DD} = 3.3V$		15		mA
I_{OH}	Output High Current	@ 2.4V, $V_{DD} = 3.3V$		15		mA
C_I	Input Capacitance	All pins except CLKIN			7	pF
C_I	Input Capacitance	CLKIN pin only		6	10	pF
R_P	Input Pull-Up Resistor			500		kΩ
Z_{OUT}	Clock Output Impedance			25		Ω

Note:
1. Inputs FS1:2 have a pull-up resistor; Input SSON# has a pull-down resistor.

DC Electrical Characteristics: $0°C < T_A < 70°C$, $V_{DD} = 5V \pm 10\%$

Parameter	Description	Test Condition	Min	Typ	Max	Unit
I_{DD}	Supply Current			30	50	mA
t_{ON}	Power-Up Time	First locked clock cycle after Power Good			5	ms
V_{IL}	Input Low Voltage				$0.15V_{DD}$	V
V_{IH}	Input High Voltage		$0.7V_{DD}$			V
V_{OL}	Output Low Voltage				0.4	V
V_{OH}	Output High Voltage		2.4			V
I_{IL}	Input Low Current	Note 1			−100	µA
I_{IH}	Input High Current	Note 1			10	µA
I_{OL}	Output Low Current	@ 0.4V, $V_{DD} = 5V$		24		mA
I_{OH}	Output High Current	@ 2.4V, $V_{DD} = 5V$		24		mA
C_I	Input Capacitance	All pins except CLKIN			7	pF
C_I	Input Capacitance	CLKIN pin only		6	10	pF
R_P	Input Pull-Up Resistor			500		kΩ
Z_{OUT}	Clock Output Impedance			25		Ω

AC Electrical Characteristics: $T_A = 0°C$ to $+70°C$, $V_{DD} = 3.3V \pm 0.3V$ or $5V \pm 10\%$

Parameter	Description	Test Condition	Min	Typ	Max	Unit
f_{IN}	Input Frequency	Input Clock	28		75	MHz
f_{OUT}	Output Frequency	Spread Off	28		75	MHz
t_R	Output Rise Time	V_{DD}, 15-pF load 0.8V–2.4V		2	5	ns
t_F	Output Fall Time	V_{DD}, 15-pF load 2.4V–0.8V		2	5	ns
t_{OD}	Output Duty Cycle	15-pF load	40		60	%
t_{ID}	Input Duty Cycle		40		60	%
t_{JCYC}	Jitter, Cycle-to-Cycle			250	300	ps
	Harmonic Reduction	$f_{out} = 40$ MHz, third harmonic measured, reference board, 15-pF load	8			dB

Application Information

Recommended Circuit Configuration

For optimum performance in system applications the power supply decoupling scheme shown in *Figure 4* should be used.

V_{DD} decoupling is important to both reduce phase jitter and EMI radiation. The 0.1-µF decoupling capacitor should be placed as close to the V_{DD} pin as possible, otherwise the in-creased trace inductance will negate its decoupling capability. The 10-µF decoupling capacitor shown should be a tantalum type. For further EMI protection, the V_{DD} connection can be made via a ferrite bead, as shown.

Recommended Board Layout

Figure 5 shows a recommended 2-layer board layout.
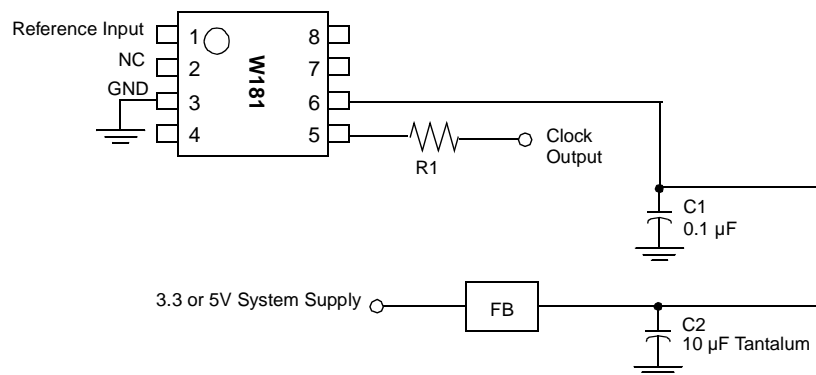
Figure 4. Recommended Circuit Configuration

C1 = High frequency supply decoupling capacitor (0.1-µF recommended).

C2 = Common supply low frequency decoupling capacitor (10-µF tantalum recommended).

R1 = Match value to line impedance

FB = Ferrite Bead

G = Via To GND Plane
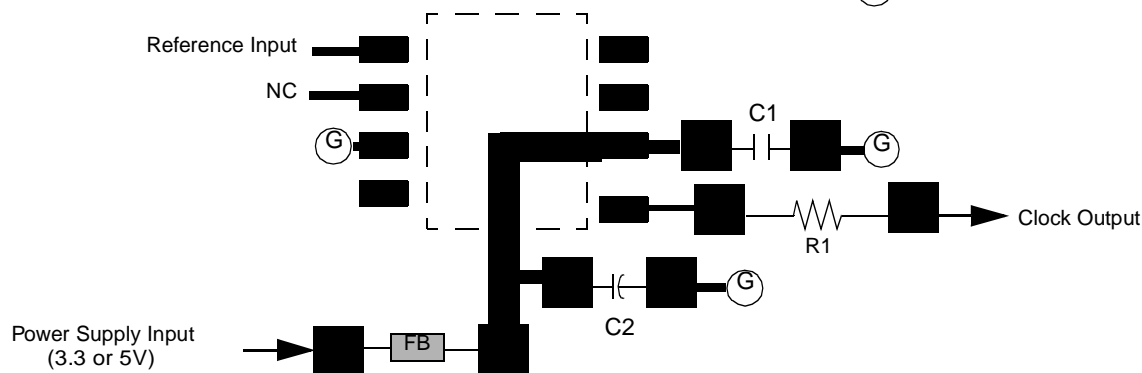
Figure 5. Recommended Board Layout (2-Layer Board)

Ordering Information

Ordering Code	Freq. Mask Code	Package Name	Package Type
W181	01, 02, 03	G	8-pin Plastic SOIC (150-mil)
W181	01	X	14-pin Plastic TSSOP

Document #: 38-00790-A

Package Diagram

14-pin Thin Shrink Small Outline Package

TOP VIEW

SIDE VIEW

DETAIL 'A'
(SCALE: 30/1)

DETAIL "B"
(SCALE: 30/1)
DAMBAR PROTRUSION

DETAIL "C"
SCALE: 120/1

(SEE NOTE 9)

END VIEW

NOTES:

1. DIE THICKNESS ALLOWABLE IS 0.279±0.0127 (.0110±.0005 INCHES)
2. DIMENSIONING & TOLERANCES PER ANSI Y14.5M-1982.
3. "T" IS A REFERENCE DATUM.
4. "D" & "E" ARE REFERENCE DATUMS AND DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS, AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15mm PER SIDE.
5. DIMENSION IS THE LENGTH OF TERMINAL FOR SOLDERING TO A SUBSTRATE.
6. TERMINAL POSITIONS ARE SHOWN FOR REFERENCE ONLY.
7. FORMED LEADS SHALL BE PLANAR WITH RESPECT TO ONE ANOTHER WITHIN 0.076mm AT SEATING PLANE.
8. THE LEAD WIDTH DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND AN ADJACENT LEAD TO BE 0.14mm SEE DETAILS 'B' AND 'C'.
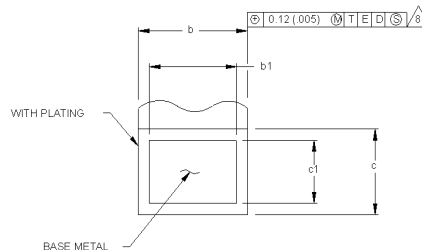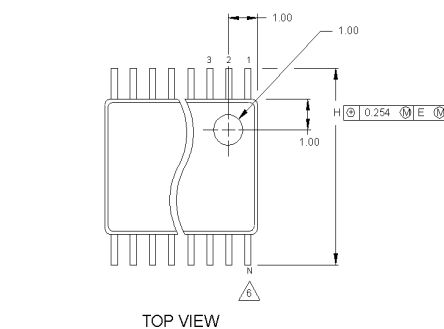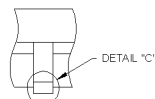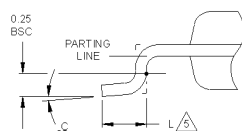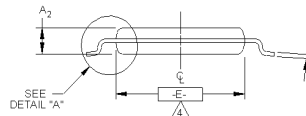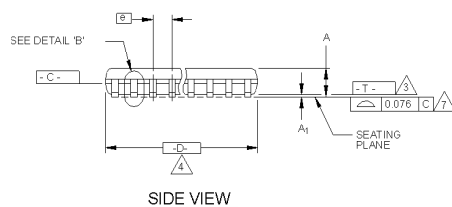9. DETAIL "C" TO BE DETERMINED AT 0.10 TO 0.25 MM FROM THE LEAD TIP.
10. CONTROLLING DIMENSION: MILLIMETERS.
11. THIS PART IS COMPLIANT WITH JEDEC SPECIFICATION MO-153. VARIATIONS AA, AB, AC, AD AND AE.

THIS TABLE IN MILLIMETERS

SYMBOL	COMMON DIMENSIONS			NOTE	VARI-ATIONS	4 D			6 N
	MIN.	NOM.	MAX.			MIN.	NOM.	MAX.	
A			1.10		AA	2.90	3.00	3.10	8
A1	0.05	0.10	0.15		AB	4.90	5.00	5.10	14
A2	0.85	0.90	0.95		AC	4.90	5.00	5.10	16
b	0.19	-	0.30	8	AD	6.40	6.50	6.60	20
b1	0.19	0.22	0.25		AE	7.70	7.80	7.90	24
c	0.090	-	0.20		AF	9.60	9.70	9.80	28
c1	0.090	0.127	0.135						
D	SEE VARIATIONS			4					
E	4.30	4.40	4.50	4					
e	0.65 BSC								
H	6.25	6.40	6.50						
L	0.50	0.60	0.70	5					
N	SEE VARIATIONS			6					
α	0°	4°	8°						

THIS TABLE IN INCHES

SYMBOL	COMMON DIMENSIONS			NOTE	VARI-ATIONS	4 D			6 N
	MIN.	NOM.	MAX.			MIN.	NOM.	MAX.	
A			.0433		AA	.114	.118	.122	8
A1	.002	.004	.006		AB	.193	.197	.201	14
A2	.0335	.0354	.0374		AC	.193	.197	.201	16
b	.0075	-	.0118	8	AD	.252	.256	.260	20
b1	.0075	.0087	.0098		AE	.303	.307	.311	24
c	.0035	-	.0079		AF	.378	.382	.386	28
c1	.0035	.0050	.0053						
D	SEE VARIATIONS			4					
E	.169	.173	.177	4					
e	.0256 BSC								
H	.246	.252	.256						
L	.020	.024	.028	5					
N	SEE VARIATIONS			6					
α	0°	4°	8°						

VARIATION AF IS DESIGNED BUT NOT TOOLED

Package Diagram (continued)

8-Pin Small Outline Integrated Circuit (SOIC, 150 mils)

TOP VIEW

BOTTOM VIEW

SIDE VIEW

END VIEW

SEE DETAIL A

DETAIL A

NOTES:

1. MAXIMUM DIE THICKNESS ALLOWABLE IS .015.

2. DIMENSIONING & TOLERANCES PER ANSI.Y14.5M - 1982.

3. "T" IS A REFERENCE DATUM.

4. "D" & "E" ARE REFERENCE DATUMS AND DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS, BUT DOES INCLUDE MOLD MISMATCH AND ARE MEASURED AT THE MOLD PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.006 INCHES PER SIDE.

5. "L" IS THE LENGTH OF TERMINAL FOR SOLDERING TO A SUBSTRATE.

6. "N" IS THE NUMBER OF TERMINAL POSITIONS.

7. TERMINAL POSITIONS ARE SHOWN FOR REFERENCE ONLY.

8. FORMED LEADS SHALL BE PLANAR WITH RESPECT TO ONE ANOTHER WITHIN .003 INCHES AT SEATING PLANE.

9. THE APPEARANCE OF PIN #1 I.D ON THE 8 LD IS OPTIONAL, ROUND TYPE ON SINGLE LEADFRAME AND RECTANGULAR TYPE ON MATRIX LEADFRAME.

10. COUNTRY OF ORIGIN LOCATION AND EJECTOR PIN ON PACKAGE BOTTOM IS OPTIONAL AND DEPEND ON ASSEMBLY LOCATION.

11. CONTROLLING DIMENSION: INCHES.

THIS TABLE IN INCHES

SYMBOL	COMMON DIMENSIONS			NOTE	NOTE VARI-ATIONS	D			N
	MIN.	NOM.	MAX.			MIN.	NOM.	MAX.	
A	.061	.064	.068		AA	.189	.194	.196	8
A₁	.004	.006	.0098		AB	.337	.342	.344	14
A₂	.055	.058	.061		AC	.386	.391	.393	16
B	.0138	.016	.0192						
C	.0075	.008	.0098						
D	SEE VARIATIONS			3					
E	.150	.155	.157						
e	.050 BSC								
H	.230	.236	.244						
h	.010	.013	.016						
L	.016	.025	.035						
N	SEE VARIATIONS			5					
∝	0°	5°	8°						
X	.085	.093	.100						

THIS TABLE IN MILLIMETERS

SYMBOL	COMMON DIMENSIONS			NOTE	NOTE VARI-ATIONS	D			N
	MIN.	NOM.	MAX.			MIN.	NOM.	MAX.	
A	1.55	1.63	1.73		AA	4.80	4.93	4.98	8
A₁	0.127	0.15	0.25		AB	8.58	8.69	8.74	14
A₂	1.40	1.47	1.55		AC	9.80	9.93	9.98	16
B	0.35	0.41	0.49						
C	0.19	0.20	0.25						
D	SEE VARIATIONS			3					
E	3.81	3.94	3.99						
e	1.27 BSC								
H	5.84	5.99	6.20						
h	0.25	0.33	0.41						
L	0.41	0.64	0.89						
N	SEE VARIATIONS			5					
∝	0°	5°	8°						
X	2.16	2.36	2.54						